## NSN 5962-00-497-0206

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Body Length:	
0.896 inches	
Body Width:	
Between 0.220 inches and 0.310 inches	
Body Height:	
Between 0.140 inches and 0.185 inches	
Maximum Power Dissipation Rating:	
625.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and monolithic and positive	e outputs and w/enable and programmable and programmed and bipolar and w/buffered
putput and w/decoded output and expandable a	and wire-or outputs
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Fransistor-transistor logic	
Input Circuit Pattern:	
input	
Case Outline Source And Designator:	
D-2 mil-m-38510	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic	:
5.5 volts power source	
Time Rating Per Chacteristic:	
50.00 nanoseconds propagation delay time, lo	ow to high level output
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
49956-461442 drawing (this is the basic goverr	ning drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other c	document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:	
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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## Demilitarization:

Yes - demil/mli

Fiig:

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